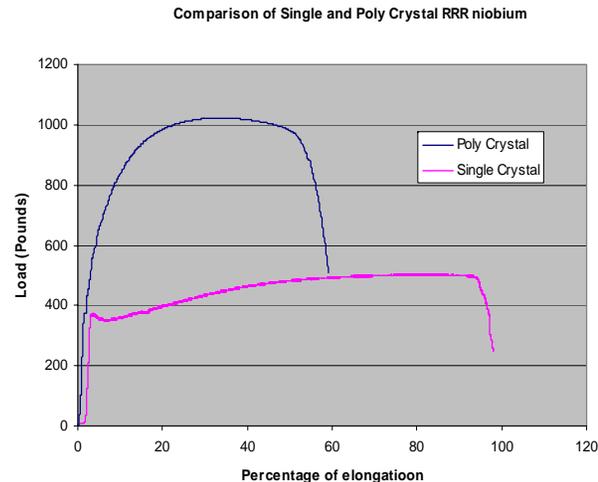


Performance of Large Grain and Single Crystal Niobium Cavities

P. Kneisel, G. Ciovati, G.R.Myneni, Jlab
J. Sekutowicz, DESY
T. Carneiro, CBMM

Jlab/CBMM Technology(1)

- Development started with the need for understanding mechanical properties of niobium from different manufacturers (*G. Myneni*)
- Ingot material supplied by CBMM with large grains (*T. Carneiro*)
- Mechanical properties -especially elongation - excellent, permitting forming of cavity cells
- Investigate influence of grain boundaries on "Q-drop"



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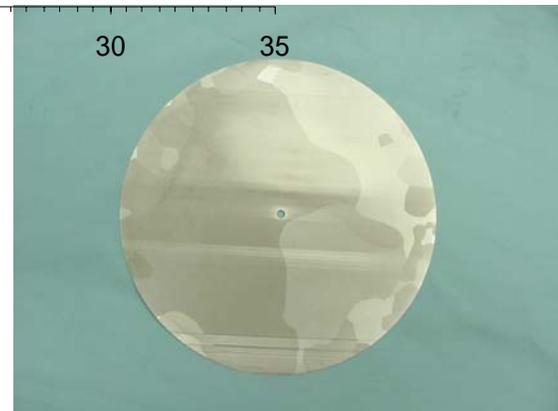
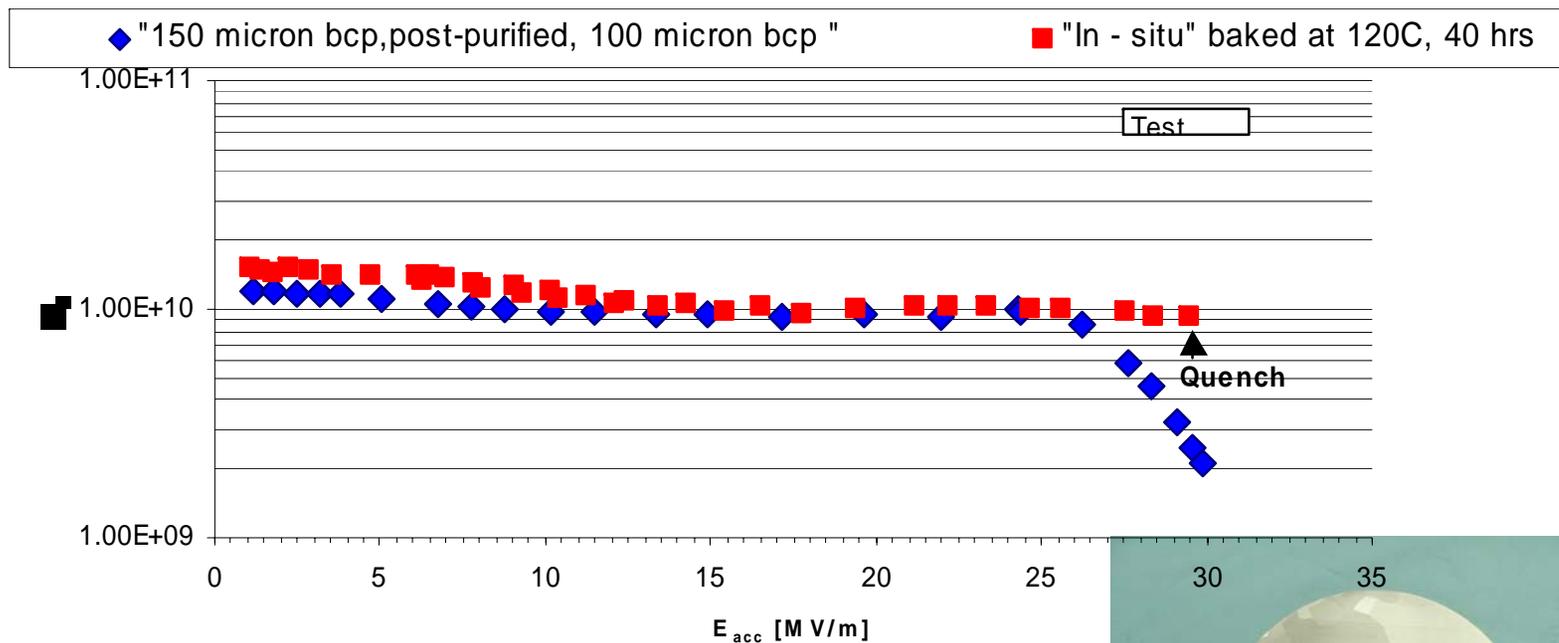
Jlab/CBMM Technology(2)

- Since the first ILC workshop we have fabricated and tested 5 single cell cavities (1300 MHz - 1500 MHz) from sliced material (wire EDM and saw cut) from 3 different ingots ("A","B","C"), 3 different shapes, CBMM
- We have fabricated and tested 2 single crystal cavities from ingot "A" at 2.3 GHz, CBMM
- We have fabricated two 2.3 GHz cavities with material from a second vendor (WC) with somewhat smaller grains (not yet tested)
- We have fabricated a single cell cavity from large grain niobium from China-Ningxia (not yet tested)
- We have fabricated a 7-cell HG -Jlab-Upgrade cavity, which has been tested with problems so far (leaks, FE)
- We are in the process of fabricating an ILC LL 7-cell cavity and intend to present results at the Snowmass meeting

Jlab/CBMM Technology(3)

Ingot "B"

HG Single Cell Cavity - "Single Crystal" -B
 Q_0 vs. E_{acc}



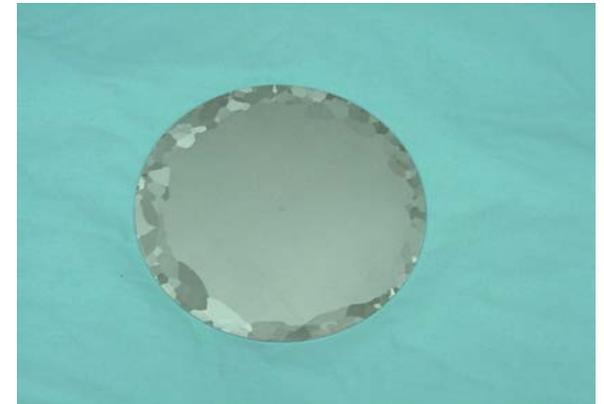
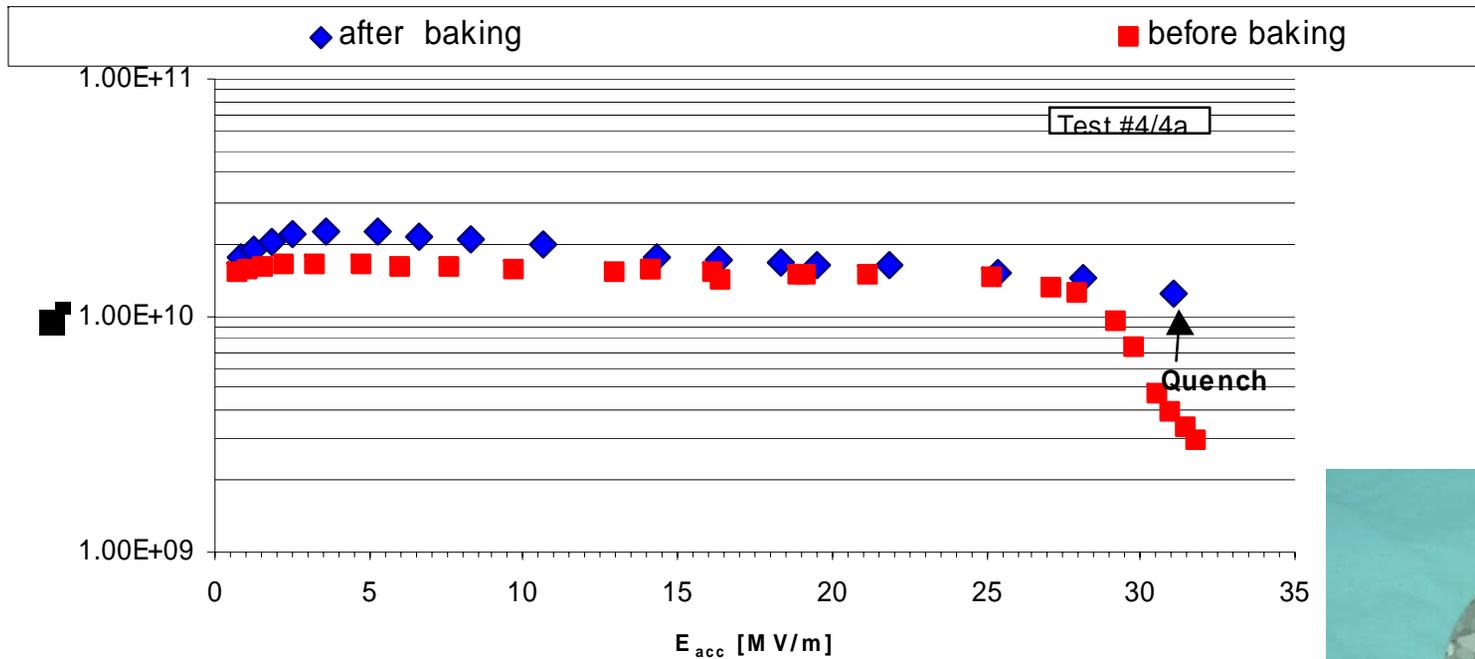
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Jlab/CBMM Technology(4)

Ingot "A"

HG Single Cell Cavity - "Single Crystal" -A
 Q_0 vs. E_{acc}



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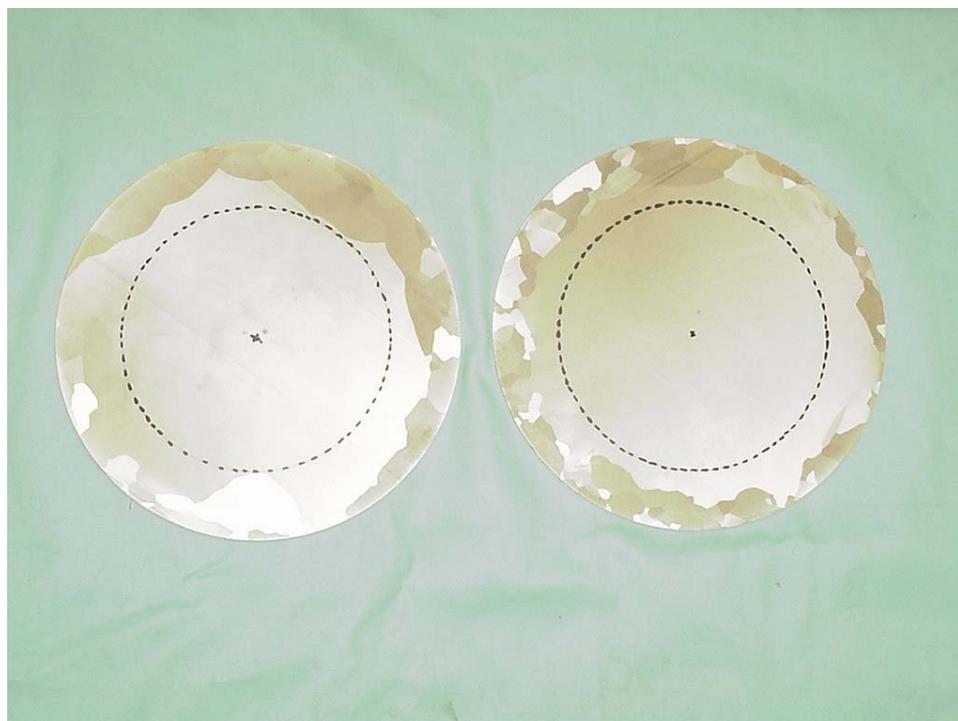
Jlab/CBMM Technology(5)

Discs from Ingot

Cavity

$$E_{\text{peak}}/E_{\text{acc}} = 1.674$$

$$H_{\text{peak}}/E_{\text{acc}} = 4.286 \text{ mT/MV/m}$$



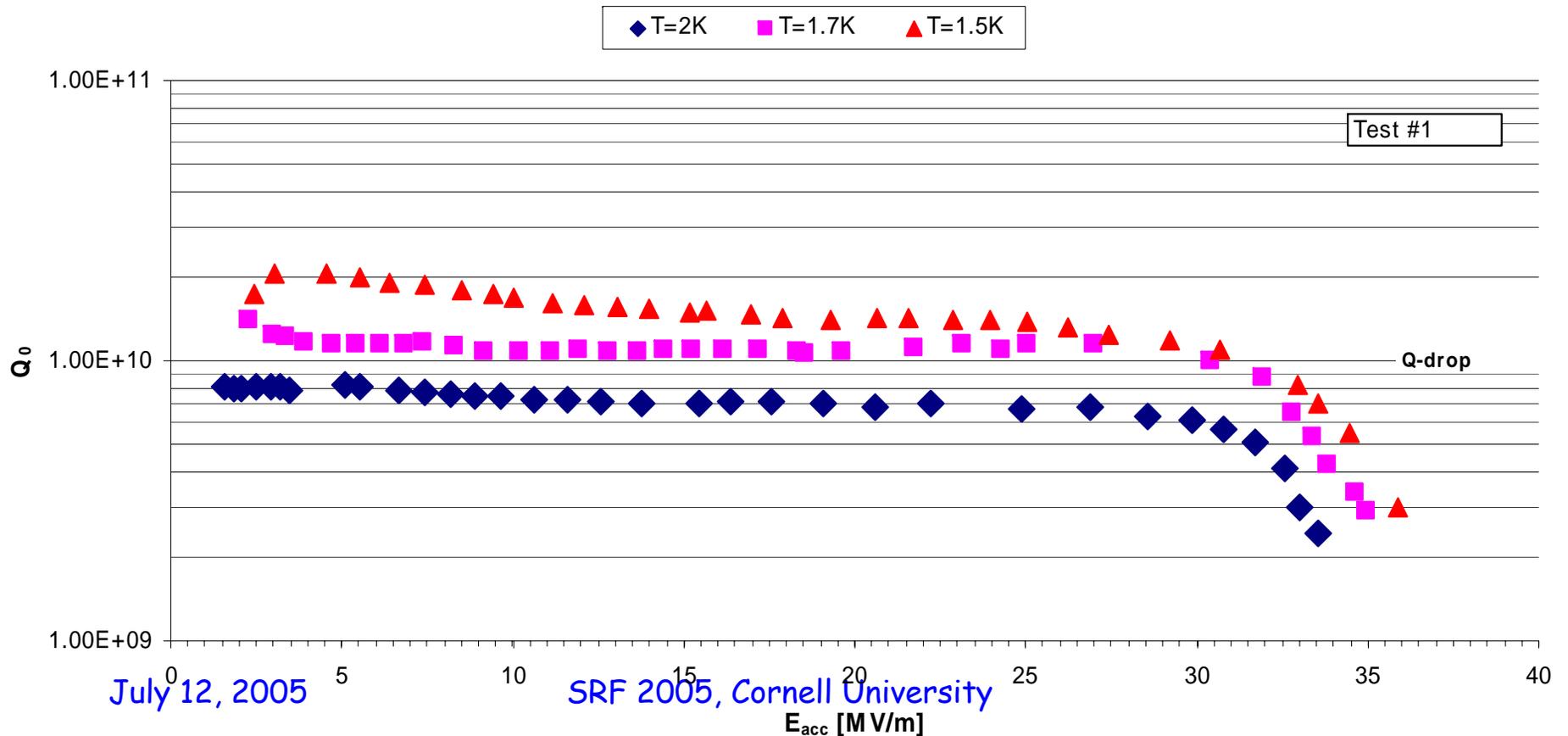
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Single Crystal Niobium Cavity (1)

Test #1a: Treatment 100 μm BCP, 800C hydrogen degassing, 100 μm BCP, high pressure rinsing for 30 min

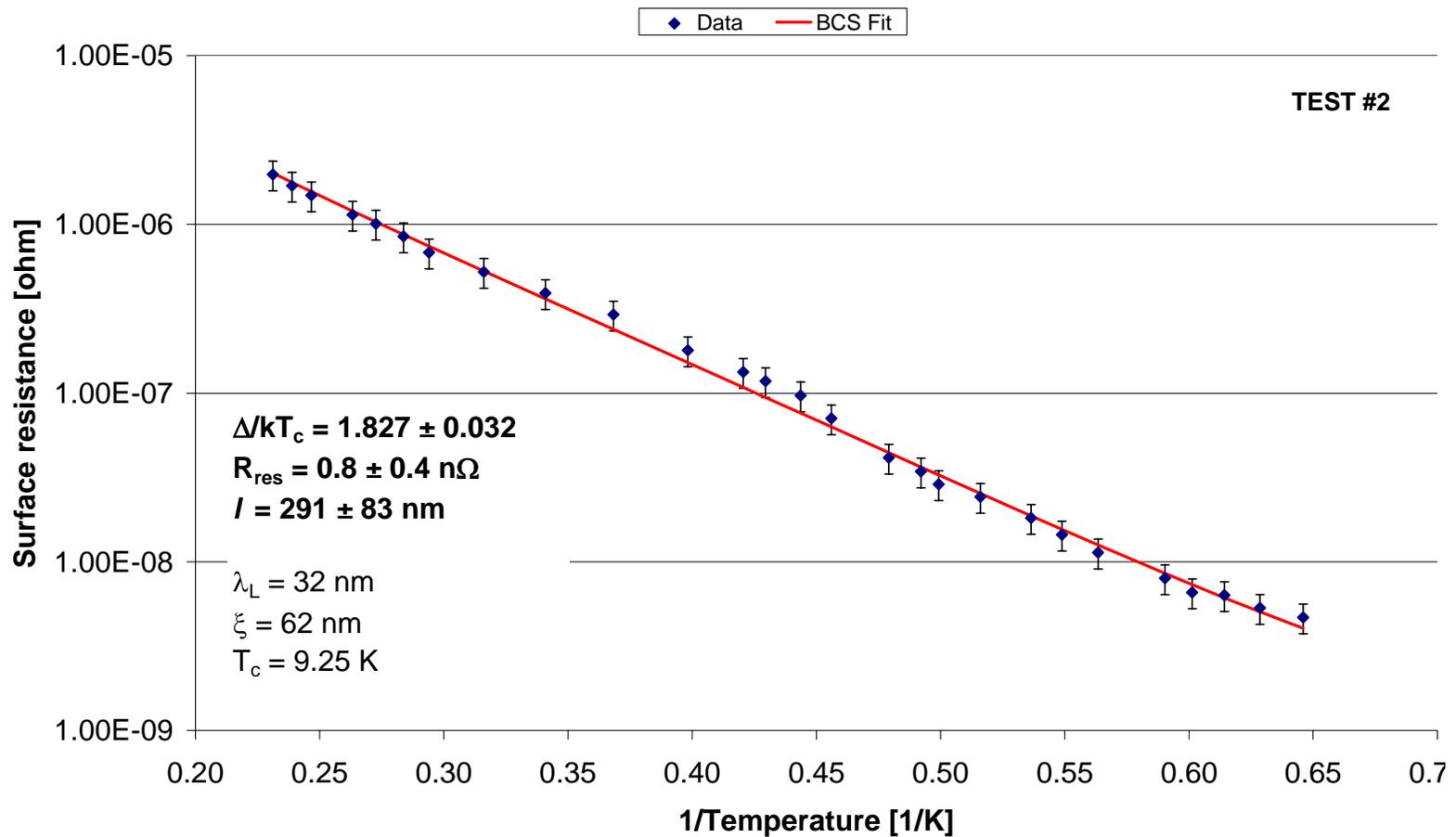
2.2 GHz Single crystal single cell cavity
 Q_0 vs. E_{acc}



Single Crystal Niobium Cavity (2)

Test #2: T-dependence (before baking)

2.2 GHz Single crystal single cell cavity after post-purification, 70mm BCP 1:1:1, 30min HPR

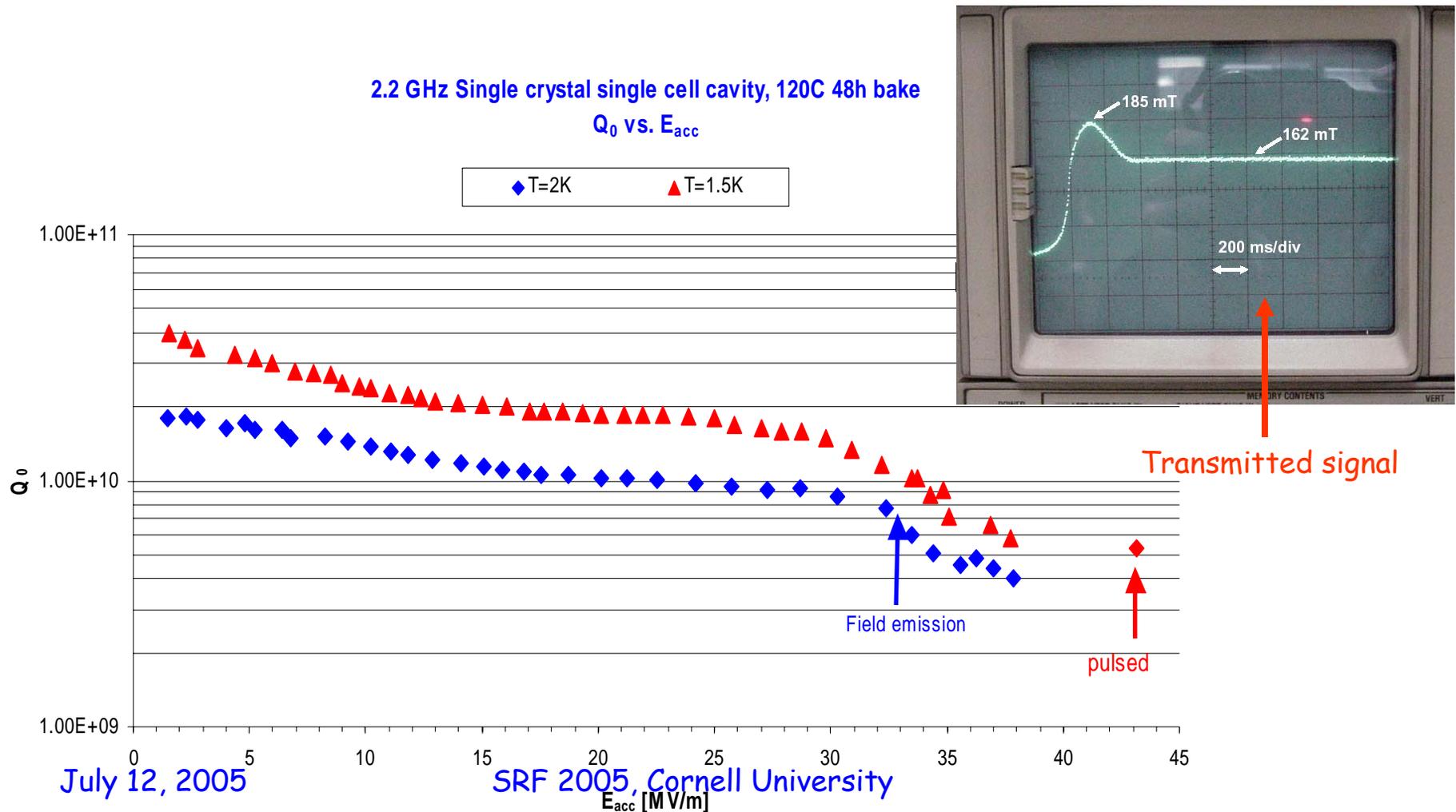


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Single Crystal Niobium Cavity (3)

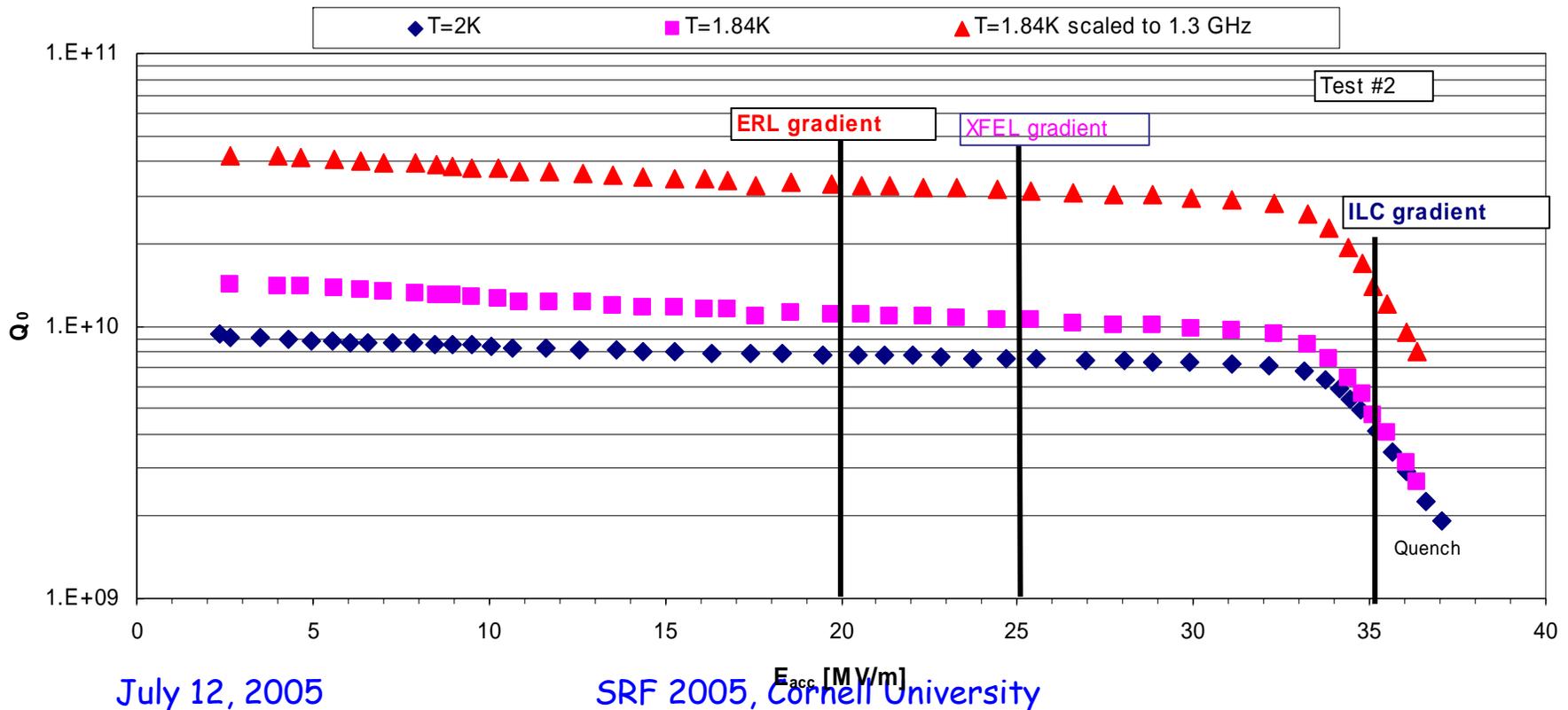
Test #1b: Treatment 100 μm BCP, 800C hydrogen degassing, 100 μm BCP, high pressure rinsing, "in situ" baked at 120C for 48 hrs



Single Crystal Niobium Cavity (4)

Test #2: post-purification heat treatment at 1250 C for 10 hrs, 100 μm BCP ,high pressure rinsing

2.2 GHz Single crystal single cell cavity after postpurification
 Q_0 vs. E_{acc}



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Jlab/CBMM Technology(6)

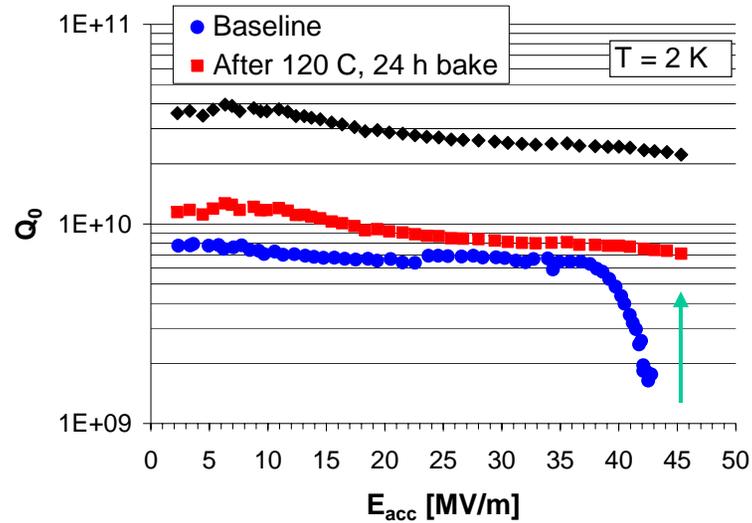
Nb Discs

LL cavity 2.3GHz



$$E_{\text{peak}}/E_{\text{acc}} = 2.072$$

$$H_{\text{peak}}/E_{\text{acc}} = 3.56 \text{ mT/MV/m}$$

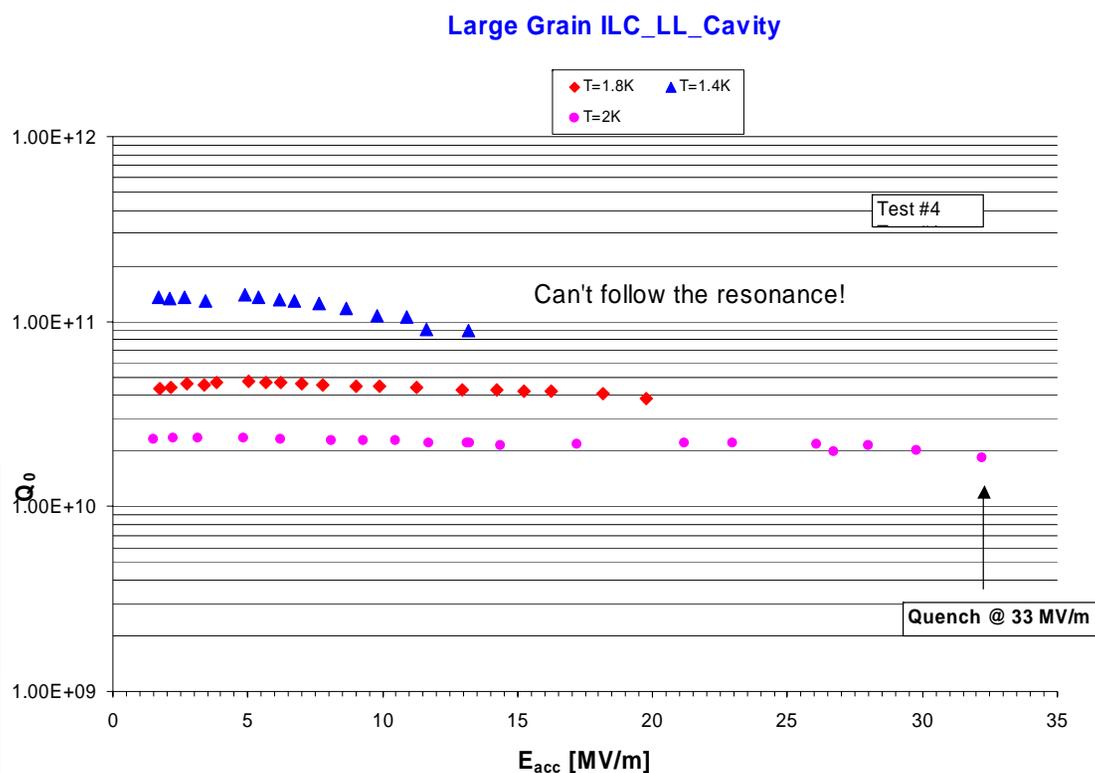


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Jlab/CBMM Technology(7)

ILC_LL Cavities: no Q-drop w/o baking



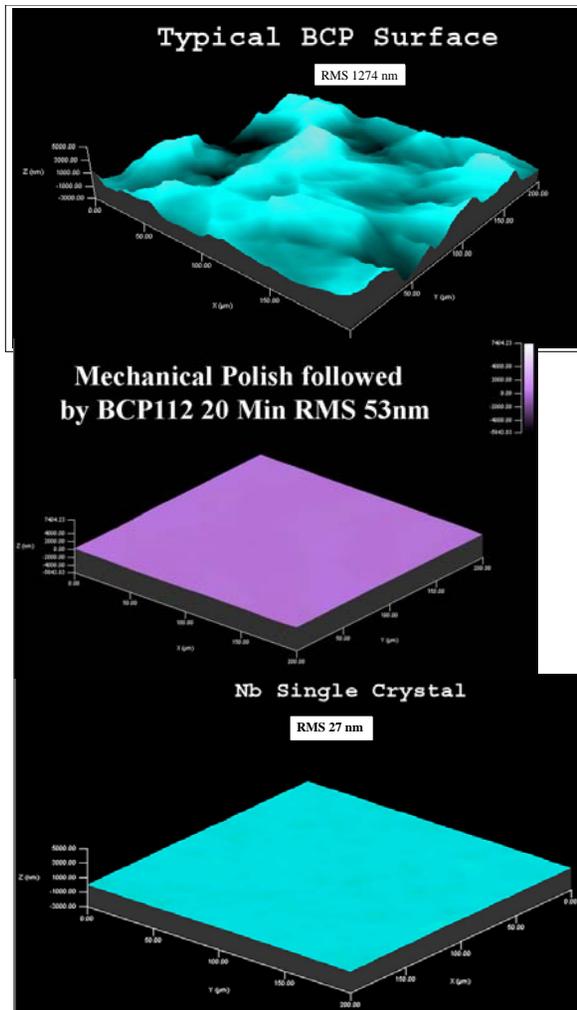
1500 ppm Ta

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Surface Roughness (1)

BCP provides very smooth surfaces as measured by A.Wu, Jlab

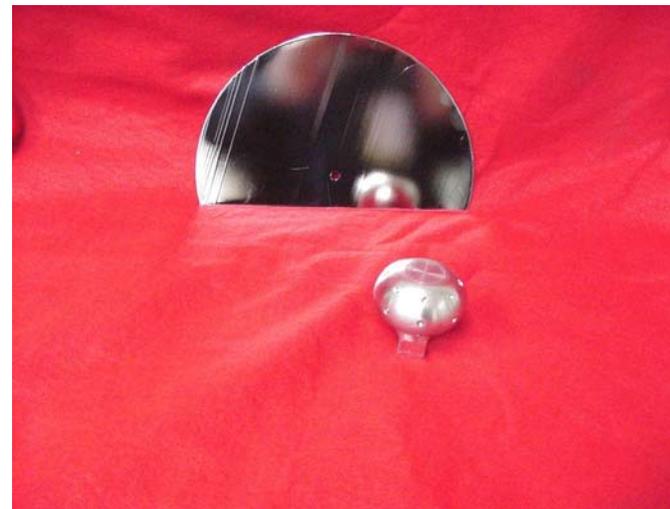


RMS: 1274 nm fine grain bcp

53 nm after ~ 35 micron, single Cryst

27 nm after ~ 80 micron, single Cryst

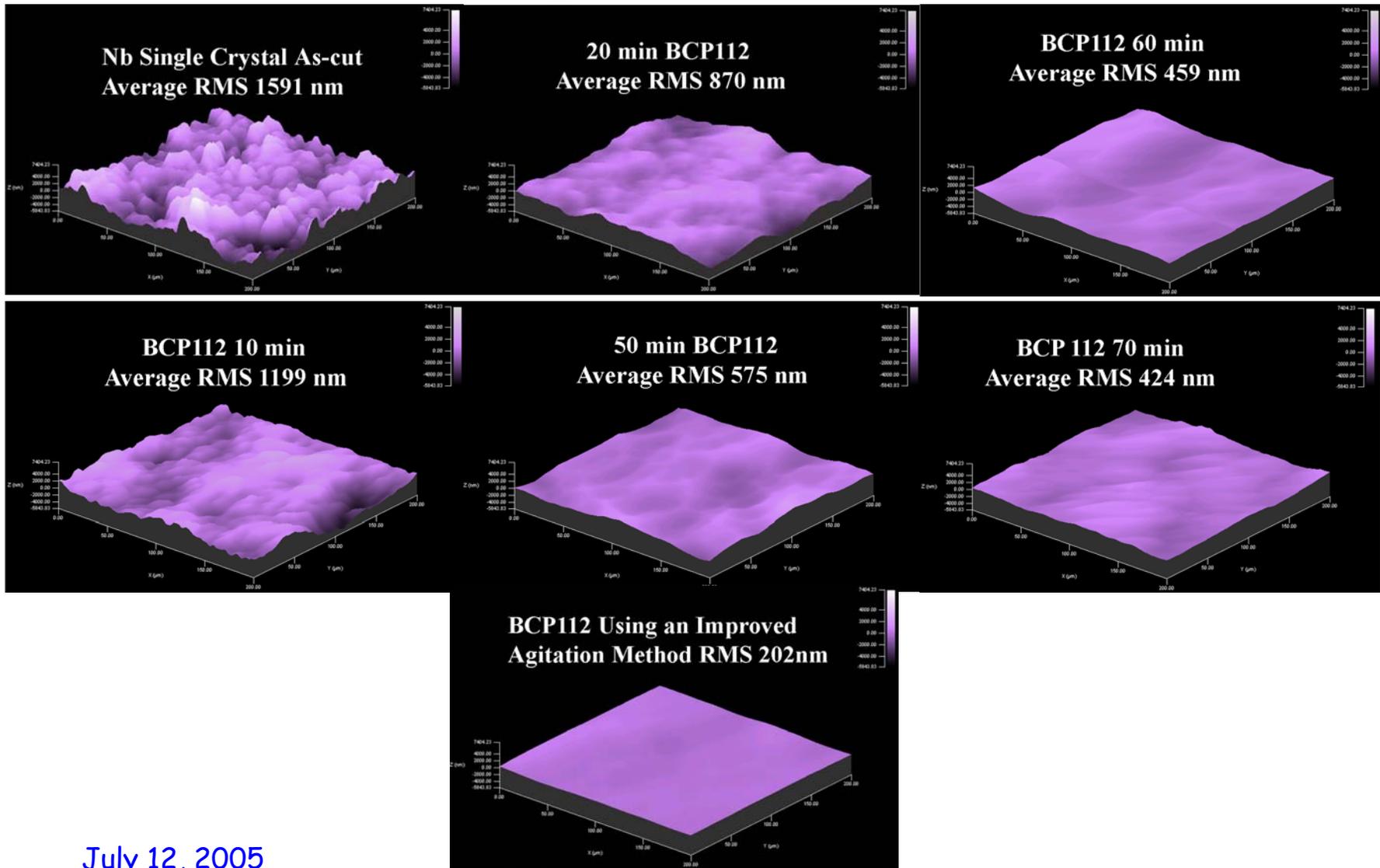
251 nm fine grain ep



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Surface Roughness (2)(A. Wu)



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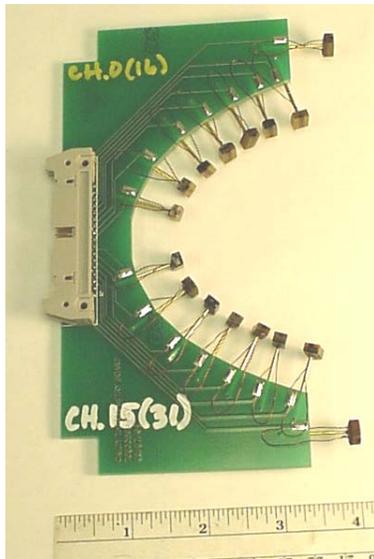
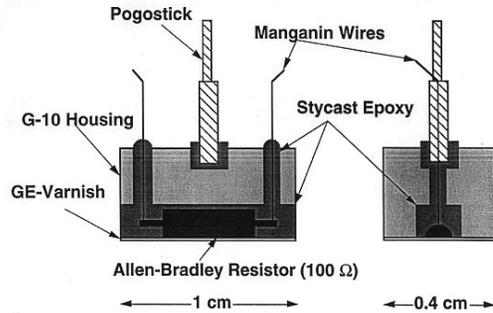
Jlab/CBMM Technology(8)

With a single cell cavity of the OC shape and fabricated from ingot "A" material we are investigating the "improvements" in cavity performance as a function of material removal employing T-mapping with the goal to:

- understand the loss mechanisms in the cavity, especially in the region of the "Q-drop"
- "streamline" the surface treatment by BCP with respect to the amount of material removal, which might result in cost savings

T-Mapping (1)

T-mapping system: ~600 Allen-Bradley C-resistors



a)

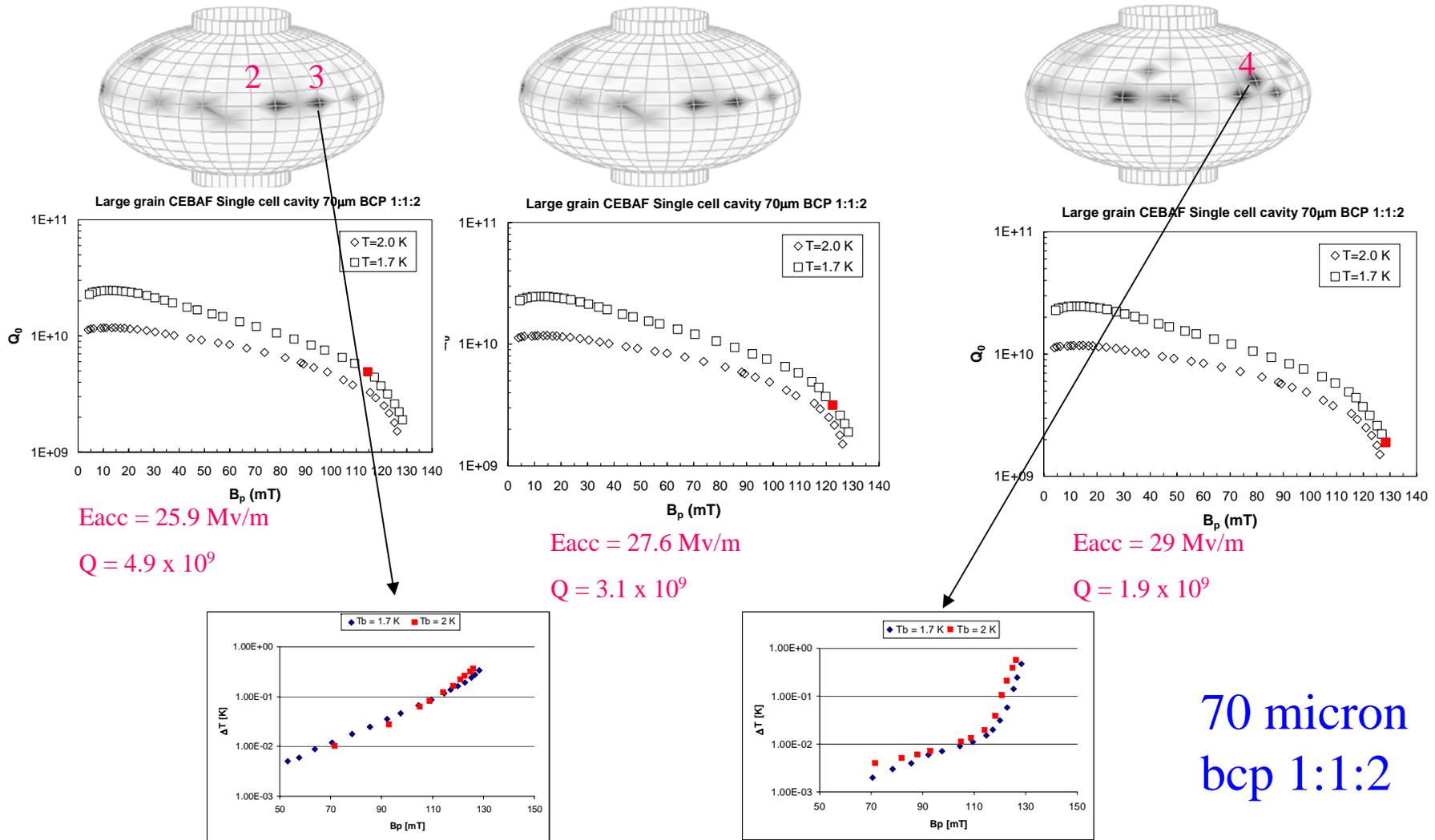


b)
)

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T-Mapping (2)



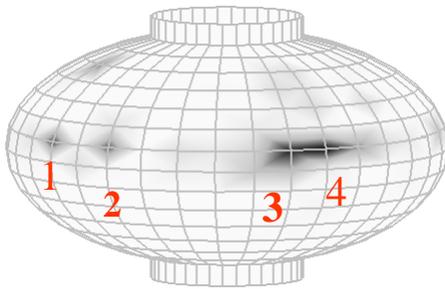
70 micron
bcp 1:1:2

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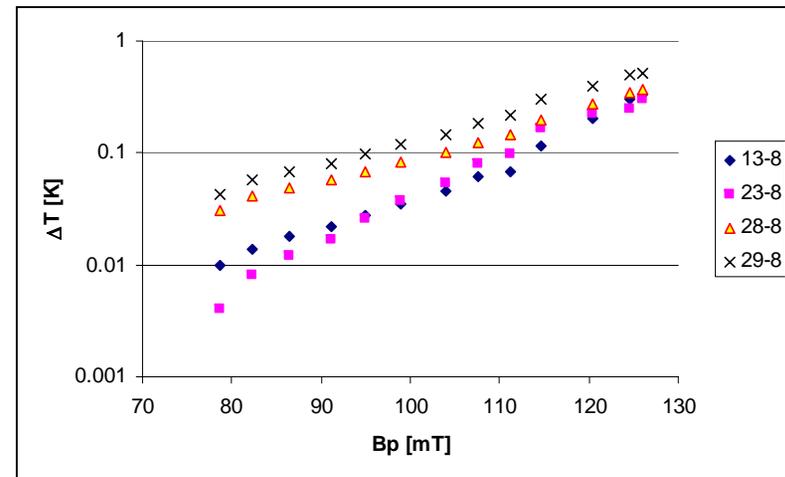
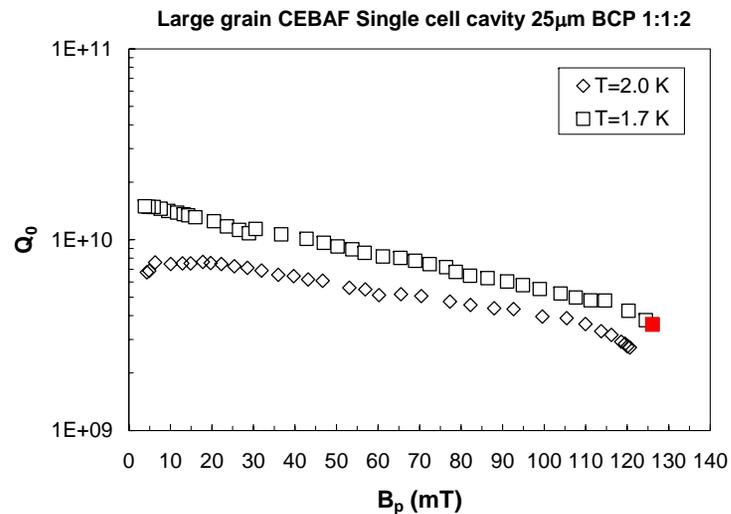
T - Mapping(3)

Add. 25 micron bcp 1:1:2



$$E_{acc} = 28.5 \text{ MV/m}$$

$$Q = 3.6 \times 10^9$$



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Jlab/CBMM Technology(9)

What are the potential advantages of large grain/single crystal niobium?

- Reduced costs
- Comparable performance
- Very smooth surfaces with BCP, no EP necessary
- Possibly elimination of "in situ" baking because of "Q-drop" onset at higher gradients
- Possibly very low residual resistances (high Q's), favoring lower operation temperature(B.Petersen)
- Higher thermal stability because of "Phonon-Peak"
- Good or better mechanical performance than fine grain material (e.g.predictable spring back..)
- Less material QA (eddy current/squid scanning)

Cavities awaiting testing

Wah Chang

2.2 GHz, HG shape



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China

1.5 GHz, OC shape



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CBMM

1.3 GHz ILC LL shape



Acknowledgement

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Pete Kushnick

Isiah Daniels